



60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C (Note 5)
60V	$5.5 \text{m}\Omega$ @ V _{GS} = 10V	100A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- High-frequency switching
- Sync rectification
- DC-DC converters

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses
- Low Q_g Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6005LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

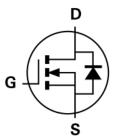
- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



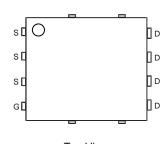




Bottom View



Internal Schematic



Top View Pin Configuration

Ordering Information (Note 4)

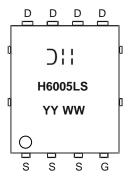
Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMTH6005LPSQ-13	PowerDI5060-8	2500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/
- 5. Package limited.



Marking Information



⊃¦¦ = Manufacturer's Marking H6005LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6)	$T_A = +25$ °C $T_A = +70$ °C	lo	20.6 17.2	А
Continuous Drain Current (Note 7)	$T_C = +25^{\circ}C \text{ (Note 5)}$ $T_C = +100^{\circ}C$	lo	100 90	А
Maximum Continuous Body Diode Forward Current (Note 7)	Is	100	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	160	А
Avalanche Current, L = 1mH		las	14.8	А
Avalanche Energy, L = 1mH		Eas	98	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _A = +25°C	P _D	3.2	W
Thermal Resistance, Junction to Ambient (Note 6)		RөJA	47	°C/W
Total Power Dissipation (Note 7)	Tc = +25°C	PD	150	W
Thermal Resistance, Junction to Case (Note 7)		Rejc	1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes:

- 5. Package limited.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).



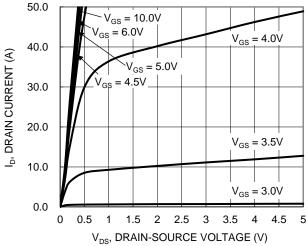
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

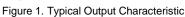
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	60		_	V	$V_{GS} = 0$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		_	1	μΑ	V _{DS} = 48V, V _{GS} = 0	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(TH)	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
			4.4	5.5		$V_{GS} = 10V, I_{D} = 50A$	
Static Drain-Source On-Resistance	RDS(ON)		5.7	7.2	mΩ	$V_{GS} = 6V, I_{D} = 20A$	
		_	7.7	10		$V_{GS} = 4.5V$, $I_D = 12.5A$	
Diode Forward Voltage	VsD	_	0.9	_	V	V _G S = 0, I _S = 50A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	2962	_		V _{DS} = 30V, V _{GS} = 0, f = 1MHz	
Output Capacitance	Coss	_	965.2	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	59.8	_			
Gate Resistance	Rg	_	0.66	_	Ω	$V_{DS} = 0$, $V_{GS} = 0$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	47.1	_		V _{DD} = 30V, I _D = 50A	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	23.1	_			
Gate-Source Charge	Qgs	_	10.2	_	nC		
Gate-Drain Charge	Q _{gd}	_	12.5	_			
Turn-On Delay Time	td(ON)		8.3	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 30A, R_{G} = 3.3\Omega$	
Turn-On Rise Time	t _R	_	9.4	_			
Turn-Off Delay Time	tD(OFF)	_	22	_	ns		
Turn-Off Fall Time	tF	_	8.9	_			
Body Diode Reverse-Recovery Time	trr		40.4	_	ns	004 4544 40044	
Body Diode Reverse-Recovery Charge	Q _{RR}	_	49.7	_	nC	- I _F = 30A, di/dt = 100A/μs	

Notes:

^{8.} Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.







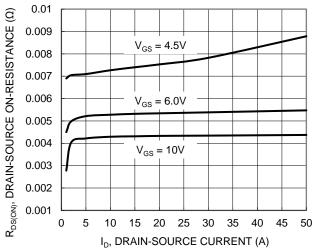


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

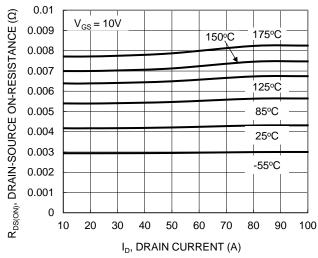


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

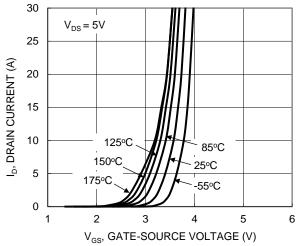


Figure 2. Typical Transfer Characteristic

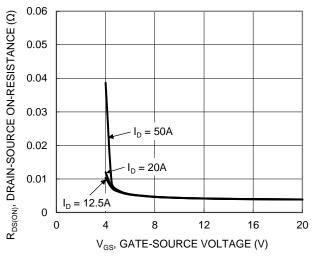


Figure 4. Typical Transfer Characteristic

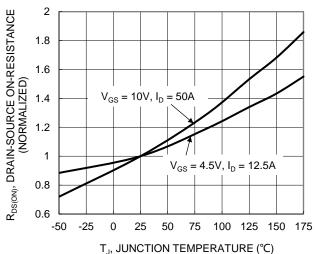


Figure 6. On-Resistance Variation with Junction Temperature



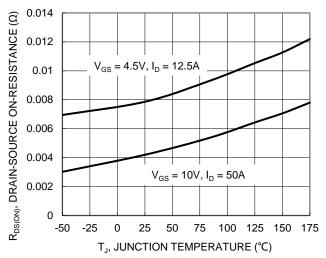


Figure 7. On-Resistance Variation with Junction Temperature

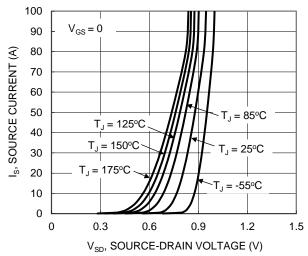


Figure 9. Diode Forward Voltage vs. Current

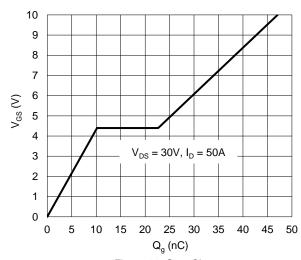


Figure 11. Gate Charge

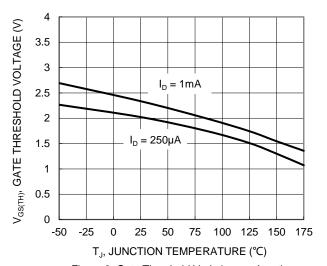


Figure 8. Gate Threshold Variation vs. Junction Temperature

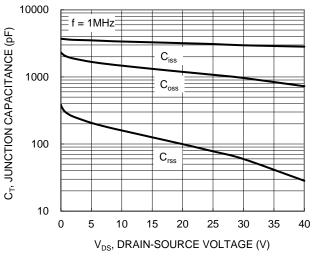


Figure 10. Typical Junction Capacitance

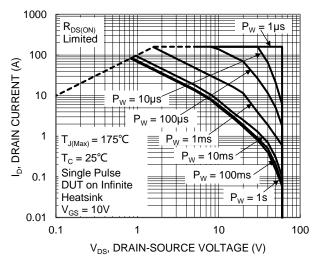


Figure 12. SOA, Safe Operation Area



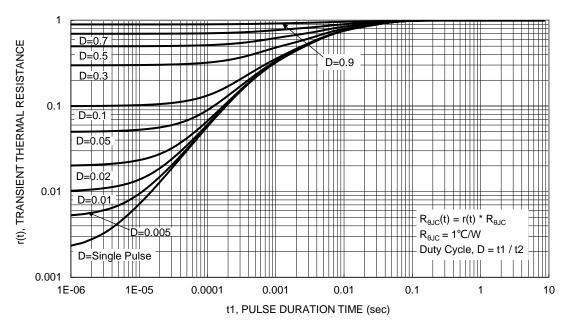


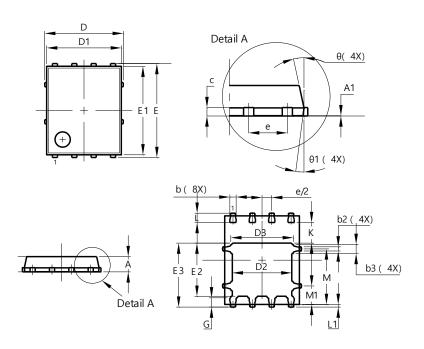
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

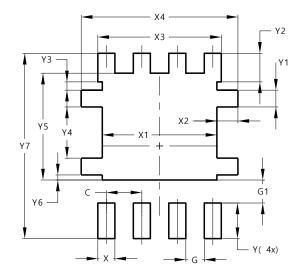


PowerDI5060-8					
Dim	Min Max		Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	į	5.15 BSC	,		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(6.15 BSC	,		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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